



40V PNP LOW VCESAT TRANSISTOR IN PowerDI3333-8

Features

- $BV_{CEO} > -40V$
- Small Form Factor Thermally Efficient Package. **Enables Higher Density End Products**
- I_C = -2A Continuous Collector Current
- I_{CM} = -3A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -320mV @ -1A
- Complementary NPN Type: DXTN22040DFGQ
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTP22040DFGQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

Mechanical Data

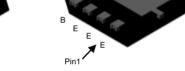
- Case: PowerDI®3333-8
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.03 grams (Approximate)

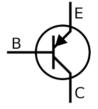
Applications

- High-Side Switch
- Supply Line Switching
- Motor Driving

PowerDI3333-8 (SWP) (Type UX)







Bottom View Top View

Device Symbol

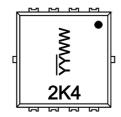
Ordering Information (Note 4)

| Part Number | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity Per Reel |
|-----------------|------------|---------|--------------------|-----------------|-------------------|
| DXTP22040DFGQ-7 | Automotive | 2K4 | 7 | 12 | 2,000 |

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2K4 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|------------------------------|------------------|-------|------|--|
| Collector-Base Voltage | V _{CBO} | -50 | V | |
| Collector-Emitter Voltage | V _{CEO} | -40 | V | |
| Emitter-Base Voltage | V _{EBO} | -7 | V | |
| Continuous Collector Current | Ic | -2 | A | |
| Peak Pulse Collector Current | I _{CM} | -3 | | |
| Continuous Base Current | I _B | -100 | mA | |
| Peak Pulse Base Current | I _{BM} | -200 | | |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|---|----------------------------------|------------------|------|------|
| | (Note 5) | | 1.07 | W |
| Power Dissipation | (Note 6) | P _D | 2.3 | W |
| | (Note 7) | | 3.4 | W |
| | (Note 5) | | 140 | °C/W |
| Thermal Resistance, Junction to Ambient | (Note 6) | R _{0JA} | 65 | °C/W |
| | (Note 7) | | 44 | °C/W |
| Thermal Resistance, Junction to Leads (Note 8 | $R_{\theta JL}$ | 11 | °C/W | |
| Operating and Storage Temperature Range | T _{J,} T _{STG} | -55 to +175 | °C | |

ESD Ratings (Note 9)

| Characteristic | | Symbol | Value | Unit | JEDEC Class |
|--|---|---------|-------|------|-------------|
| Electrostatic Discharge – Human Body Model | | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge – Machine Model | | ESD MM | 400 | V | С |
| Notes: | Notes: 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state. | | | | |

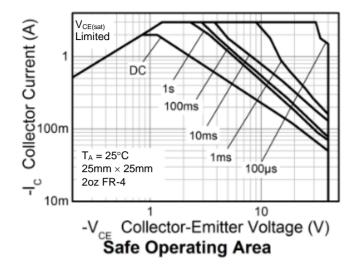
^{6.} Same as Note 5, except the device is mounted on 25mm $\times\,25\text{mm}$ 2oz copper.

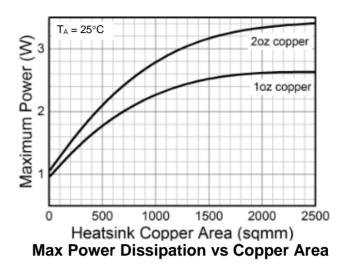
^{7.} Same as Note 5, except the device is mounted on 50mm × 50mm 2oz copper.

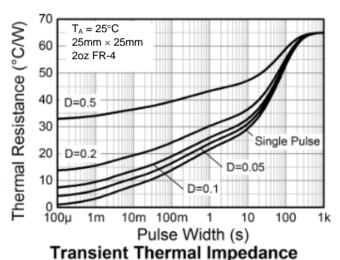
^{8.} Thermal resistance from junction to solder-point (at the collector tab). 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

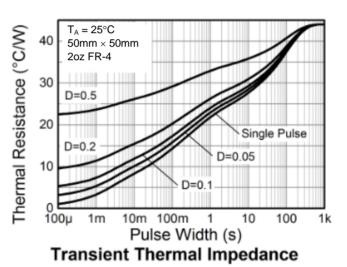


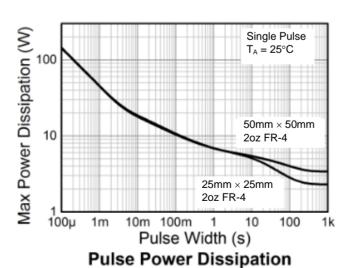
Thermal Characteristics and Derating Information

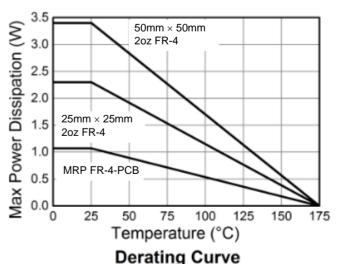














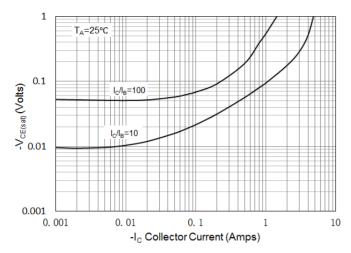
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

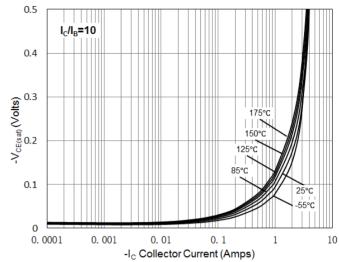
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|----------------------|--------------------------|-----------------------------------|--------------------------------------|------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | -50 | -71 | _ | ٧ | $I_{C} = -100 \mu A$ |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CEO} | -40 | -58 | _ | V | I _C = -10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | -8.5 | _ | V | I _E = -100μA |
| Collector-Base Cut-Off Current | I _{CBO} | _ | -1 -0.1 | -0.1 -20 | μΑ | V _{CB} = -50V V _{CB} = -50V, T _A = +150°C |
| Emitter-Base Cut-Off Current | I _{EBO} | _ | -1 | -20 | nA | V _{EB} = -6V |
| Collector-Emitter Cut-Off Current | ICES | _ | -1 | -20 | nA | V _{CE} = -40V, V _{BE} = 0V |
| Static Forward Current Transfer Ratio (Note 10) | h _{FE} | 340 300 200 120 | 410 354 303 203 | 900 — — | ı | $I_C = -100 \text{mA}, V_{CE} = -2 \text{V}$ $I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$ $I_C = -1 \text{A}, V_{CE} = -2 \text{V}$ $I_C = -2 \text{A}, V_{CE} = -2 \text{V}$ |
| Collector-Emitter Saturation Voltage (Note 10) | VCE(sat) | _ | -56 -48 -81 -146 -218 | -140 -170 -320 -400 -600 | mV | I _C = -100mA, I _B = -1mA I _C = -500mA, I _B = -50mA I _C = -1A, I _B = -100mA I _C = -2A, I _B = -200mA I _C = -3A, I _B = -300mA |
| Collector-Emitter Saturation Resistance (Note 10) | R _{CE(sat)} | - | _ | 320 | mΩ | $I_C = -1A$, $I_B = -100mA$ |
| Base-Emitter Saturation Voltage (Note 10) | V _{BE(sat)} | _ | -0.88 | -1 | V | $I_C = -1A$, $I_B = -100mA$ |
| Base-Emitter Turn-On Voltage (Note 10) | V _{BE(on)} | _ | -0.76 | -0.9 | V | $I_C = -1A$, $V_{CE} = -2V$ |
| Transition Frequency | f⊤ | 1 | 120 | _ | MHz | I _C = -50mA, V _{CE} = -10V f = 100MHz |
| Output Capacitance | $C_{ m obo}$ | _ | 12 | _ | pF | V _{CB} = -10V, f = 1MHz |
| | t _{delay} | _ | 10 | _ | ns | |
| Switching Characteristics | t _{rise} | 1 | 144 | _ | ns | $V_{CC} = -10V, I_{C} = -500mA$ |
| omening characteristics | t _{storage} | _ | 704 | _ | ns | $I_{B1} = -I_{B2} = -50 \text{mA}$ |
| Notes 40 Managed and and the Pulse width 4 2000 | t _{fall} | _ | 48.5 | _ | ns | |

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

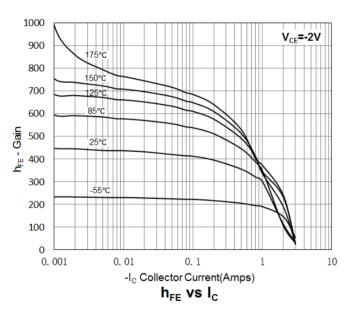


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

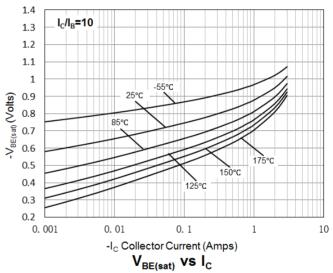


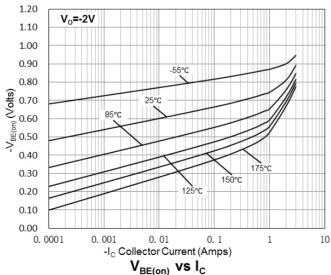


 $V_{\text{CE(sat)}} \text{ vs } I_{\text{C}}$







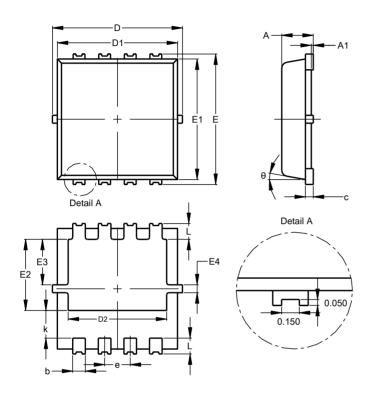




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

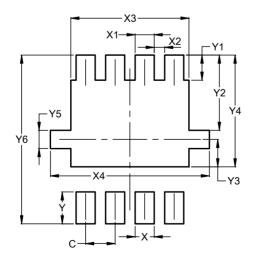


| PowerDI3333-8 (SWP) | | | | | |
|----------------------|---------|------|------|--|--|
| (Type UX) | | | | | |
| Dim | Min Max | | Тур | | |
| Α | 0.75 | 0.85 | 0.80 | | |
| A1 | 0.00 | 0.05 | | | |
| b | 0.25 | 0.40 | 0.32 | | |
| С | 0.10 | 0.25 | 0.15 | | |
| D | 3.20 | 3.40 | 3.30 | | |
| D1 | 2.95 | 3.15 | 3.05 | | |
| D2 | 2.30 | 2.70 | 2.50 | | |
| E | 3.20 | 3.40 | 3.30 | | |
| E1 | 2.95 | 3.15 | 3.05 | | |
| E2 | 1.60 | 2.00 | 1.80 | | |
| E3 | 0.95 | 1.35 | 1.15 | | |
| E4 | 0.10 | 0.30 | 0.20 | | |
| е | _ | _ | 0.65 | | |
| k | 0.50 | 0.90 | 0.70 | | |
| L | 0.30 | 0.50 | 0.40 | | |
| θ | 0° | 12° | 10° | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 0.650 |
| Х | 0.420 |
| X1 | 0.420 |
| X2 | 0.230 |
| Х3 | 2.600 |
| X4 | 3.500 |
| Y | 0.700 |
| Y1 | 0.550 |
| Y2 | 1.650 |
| Y3 | 0.600 |
| Y4 | 2.450 |
| Y5 | 0.400 |
| Y6 | 3.700 |

July 2019



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